LB11685AV

Monolithic Digital IC 3-phase Sensor Less Motor Driver

Overview

The LB11685AV is a three-phase full-wave current-linear-drive motor driver IC. It adopts a sensor less control system without the use of a Hall Effect device. For quieter operation, the LB11685AV features a current soft switching circuit and be optimal for driving the cooling fan motors used in refrigerators, etc.

Functions

- Three-phase Full-wave Linear Drive (Hall Sensor-less Method)
- Built-in Current Limiter Circuit
- Built-in Three-phase Output Voltage Control Circuit
- Built-in Motor Lock Protection Circuit
- Motor Lock Protection Detection Output
- FG Output Made by Back EMF
- Built-in Thermal Shut Down Circuit
- Beat Lock Prevention Circuit

Specifications

MAXIMUM RATINGS (T_A = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Maximum Supply Voltage	V_{CC} max		19	V
Input Applied Voltage	V_{IN} max		−0.3 to V_{CC} + 0.3	V
Maximum Output Current	I_O max (Note 1)		1.2	A
Allowable Power Dissipation	P_d max	Mounted on a board (Note 2)	1.05	W
Operating Temperature	T_{opr}		−40 to +85	°C
Storage Temperature	T_{stg}		−55 to +150	°C
Junction Temperature	T_j max		150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The I_O is a peak value of motor-current.
2. Specified board: 76.1 mm × 114.3 mm × 1.6 mm, glass epoxy board.

CAUTION: Absolute maximum ratings represent the value which cannot be exceeded for any length of time.

CAUTION: Even when the device is used within the range of absolute maximum ratings, as a result of continuous usage under high temperature, high current, high voltage, or drastic temperature change, the reliability of the IC may be degraded. Please contact us for the further details.
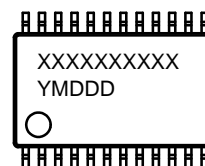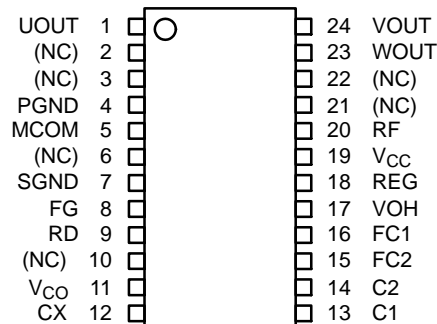
ON Semiconductor®
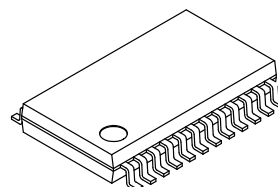
SSOP24J
CASE 565AS

MARKING DIAGRAM

XXXXXXXXXX
YMDDD

XXXXX = Specific Device Code
Y = Year
M = Month
DDD = Additional Traceability Data

PIN ASSIGNMENT

UOUT	1		24	VOUT
(NC)	2		23	WOUT
(NC)	3		22	(NC)
PGND	4		21	(NC)
MCOM	5		20	RF
(NC)	6		19	V_{CC}
SGND	7		18	REG
FG	8		17	VOH
RD	9		16	FC1
(NC)	10		15	FC2
V_{CO}	11		14	C2
CX	12		13	C1

ORDERING INFORMATION

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RECOMMENDED OPERATING CONDITIONS (T_A = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{CC}	Recommended Supply Voltage		12.0	V
V_{CC} op	Operating Supply Voltage		4.5 to 18.0	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CC}	Supply Current	FC1 = FC2 = 0 V	5	10	20	mA
VREG	Internal Regulate Voltage		3.0	3.3	3.6	V
VOSOUR	Output Voltage (Source)	I_O = 0.8 A (Note 5)		1.3	1.7	V
VOSINK	Output Voltage (Sink)	I_O = 0.8 A (Note 5)		0.5	1.3	V
VOLIM	Current Limiter		0.268	0.300	0.332	V
VINCOM	MCOM Pin Common-input Voltage Range		0		V_{CC} − 2	V
ICOM+	MCOM Pin Source Current for Hysteresis	MCOM = 7 V	30		80	µA
ICOM−	MCOM Pin Sink Current for Hysteresis	MCOM = 7 V	30		80	µA
RTCOM	MCOM Pin Hysteresis Current Ratio	RTCOM = ICOM+ / ICOM−	0.6		1.4	
I_{VCO}	VCO Input Bias Current	V_{CO} = 2.3 V			0.2	µA
f_{VCO}min	VCO Oscillation Minimum Frequency	V_{CO} = 2.1 V, CX = 0.015 µF Design target (Note 4)		930		Hz
f_{VCO}max	VCO Oscillation Maximum Frequency	V_{CO} = 2.7 V, CX = 0.015 µF Design target (Note 4)		8.6		kHz
I_{CX}	CX Charge/Discharge Current	V_{CO} = 2.5 V, CX = 1.6 V	70	100	140	µA
∆VCX	CX Hysteresis Voltage		0.35	0.55	0.75	
IC1(2)+	C1 (C2) Charge Current	V_{CO} = 2.5 V, C1(2) = 1.3 V	12	20	28	µA
IC1(2)−	C1 (C2) Discharge Current	V_{CO} = 2.5 V, C1(2) = 1.3 V	12	20	28	µA
RTC1(2)	C1 (C2) Charge/Discharge Current Ratio	RTC1(2) = IC1(2)+ / IC1(2)−	0.8	1.0	1.2	
RTCCHG	C1/C2 Charge Current Ratio	RTCCHG = IC1+ / IC2+	0.8	1.0	1.2	
RTCDIS	C1/C2 Discharge Current Ratio	RTCDIS = IC1− / IC2−	0.8	1.0	1.2	
VCW1(2)	C1 (C2) Cramp Voltage Width		1.0	1.3	1.6	V
VFGL	FG Output Low Level Voltage	IFG = 3 mA			0.5	V
VRDL	RD Output Low Level Voltage	IRD = 3 mA			0.5	V
TTSD	Thermal Shut Down Operating Temperature (Note 3)	Junction temperature Design target (Note 4)	150	180		°C
∆TTSD	Thermal Shut Down Hysteresis Temperature (Note 3)	Junction temperature Design target (Note 4)		15		°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
3. The thermal shut down circuit is built-in for protection from damage of IC. But its operation is out of T_{opr}. Design thermal calculation at normal operation.
4. Design target value and no measurement is made.
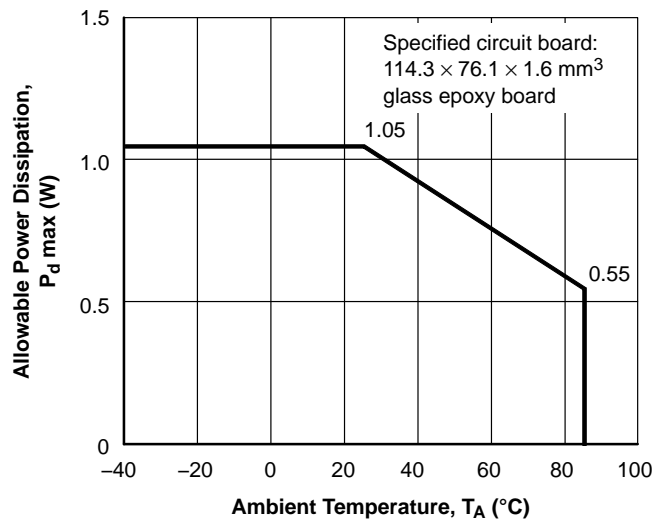5. The I_O is a peak value of motor-current.

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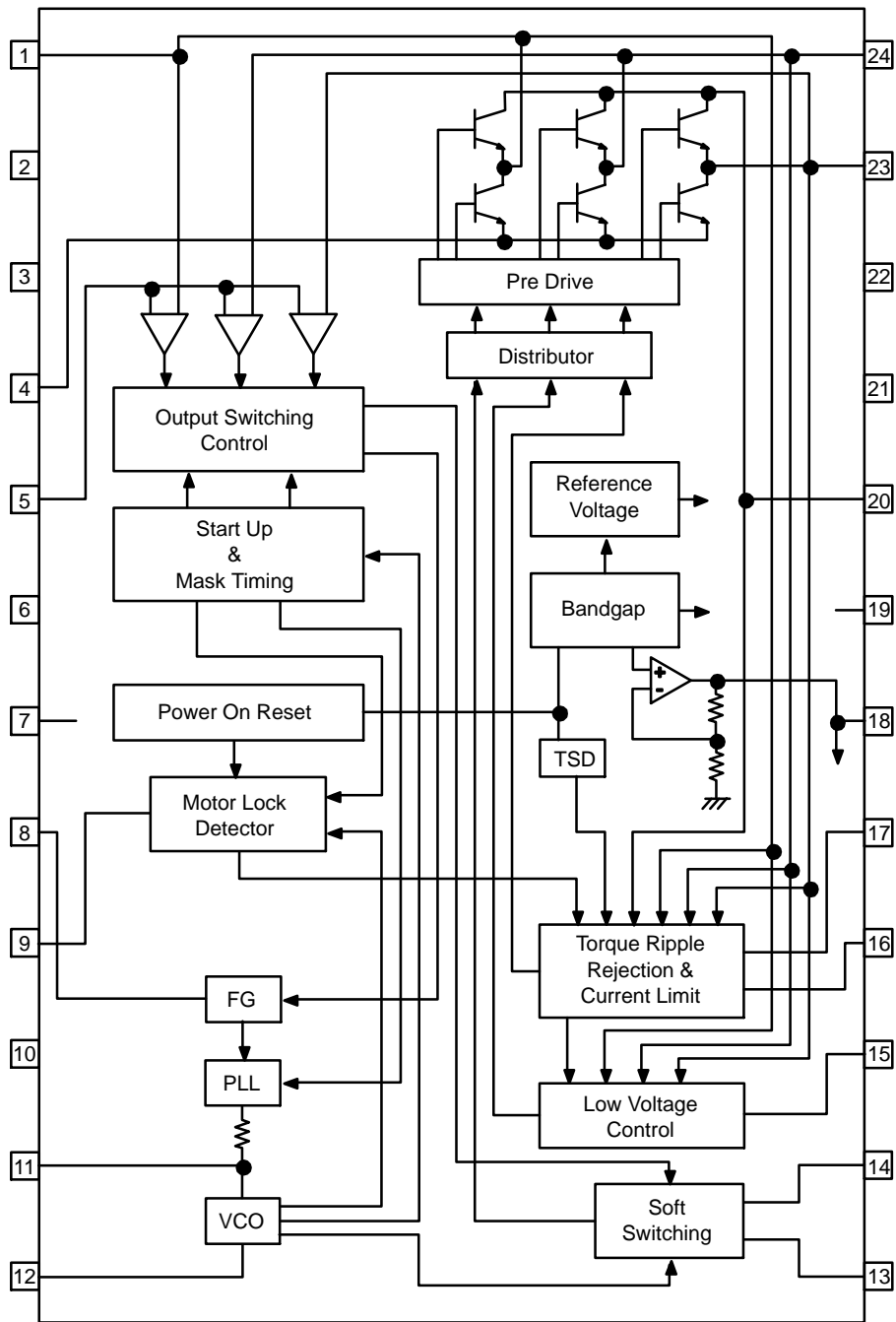

Figure 1. P_d max – T_A

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BLOCK DIAGRAM

Figure 2. Block Diagram

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PIN FUNCTION

Pin No.	Pin Name	Function	Equivalent Circuit
1 23 24	UOUT WOUT VOUT	Each output pin of three phases.	
4	PGND	GND pin in the output part. This pin is connected to GND. The SGND pin is also connected to GND	
20	RF	Pin to detect output current. By connecting a resistor between this pin and V_{CC}, the output current is detected as a voltage. The current limiter is operated by this voltage.	
5	MCOM	Motor coil midpoint input pin. The coil voltage waveform is detected based on this voltage.	
7	SGND	Ground pin (except the output part) This pin is connected to GND. The PGND pin is also connected to GND.	
8	FG	FG out made by back EMF pin. It synchronizes FG out with inverted V-phase. When don't use this function, open this pin.	
9	RD	Motor lock protection detection output pin. Output with L during rotation of motor. Open during lock protection of motor (High-impedance). When don't use this function, open this pin.	
11	VCO	PLL output pin and VCO input pin. To stabilize PLL output, connect a capacitor between this pin and GND.	

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Pin No.	Pin Name	Function	Equivalent Circuit
12	CX	VCO oscillation output pin. Operation frequency range and minimum frequency are determined by the capacity of the capacitor connected to this pin.	
13 14	C1 C2	Soft switching adjustment pin. The triangular wave from is form formed by connecting a capacitor with this pin. And, the switching of three-phase output is adjusted by the slope.	
15	FC2	Frequency characteristic correction pin 2. To suppress the oscillation of control system closed loop of sink-side, connect a capacitor between this pin and GND.	
16	FC1	Frequency characteristic correction pin 1. To suppress the oscillation of control system closed loop of source-side, connect a capacitor between this pin and GND.	
17	VOH	Three-phase output high level output pin. To stabilize the output voltage of this pin, connect a capacitor between this pin and the V_{CC} pin.	
18	VREG	DC voltage (3.3 V) output pin. Connect a capacitor between this pin and GND for stabilization.	
19	VCC	Pin to supply power-supply voltage. To curb the influence of ripple and noise. The voltage should be stabilized.	

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APPLICATION CIRCUIT EXAMPLE

* Each fixed number in the following Figure 3, is the referential value.
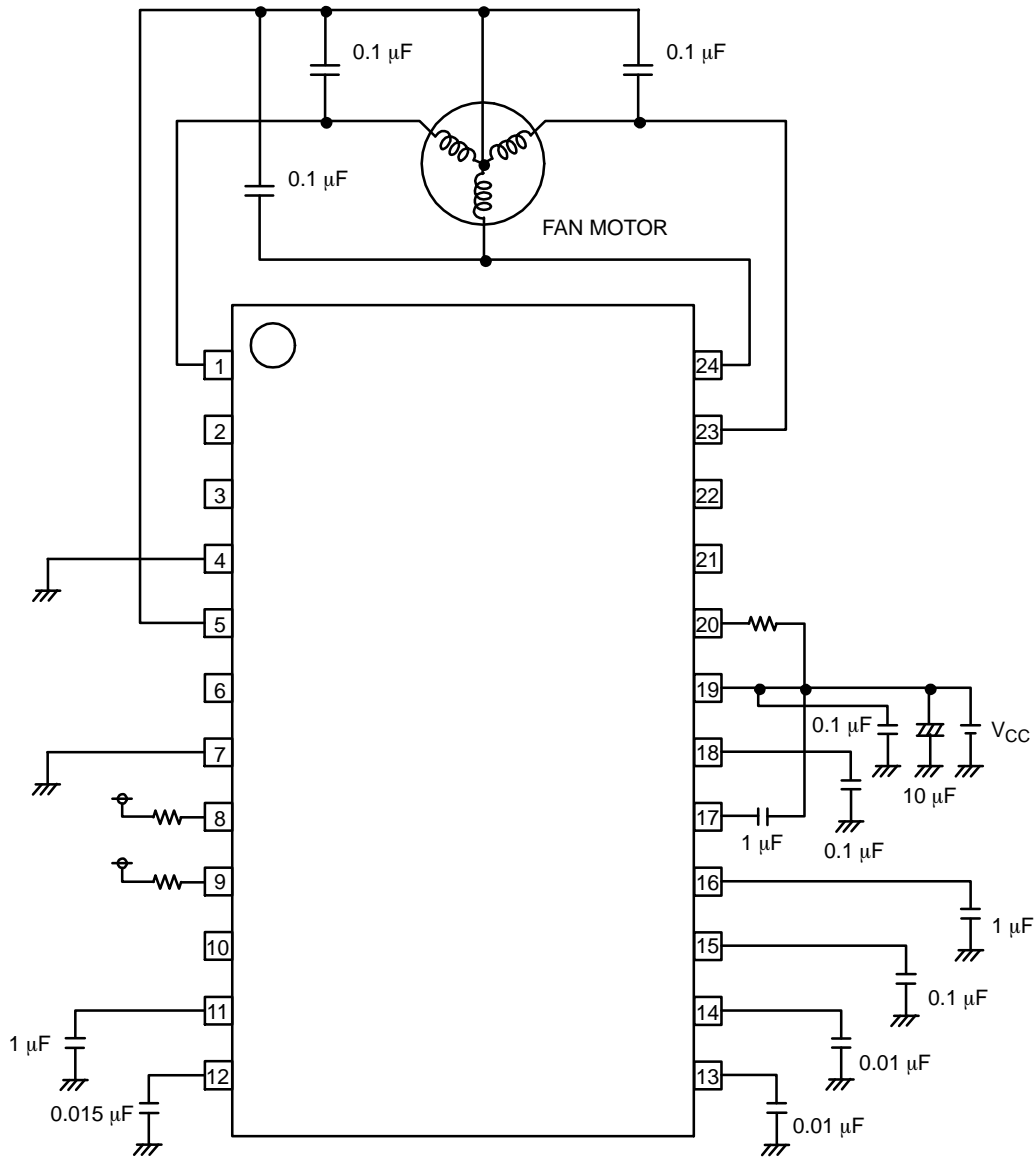
Figure 3. Application Circuit Example

ORDERING INFORMATION

Device	Package	Wire Bond	Shipping† (Qty / Packing)
LB11685AV–TLM–H	SSOP24J (275mil) (Pb-Free / Halogen Free)	Au-wire	2000 / Tape & Reel
LB11685AV–W–AH	SSOP24J (275mil) (Pb-Free / Halogen Free)	Cu-wire	2000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

SSOP24J (275mil)
CASE 565AS
ISSUE A

DATE 31 OCT 2013

10.2 MAX

9.75±0.1

24

5.6±0.1

7.6±0.25

1 2

0.8

0.3 +0.1 −0.05

⊕ 0.12 Ⓜ

(0.48)

0~10°

0.5±0.2

0.15 +0.1 −0.05

1.5 MAX

(1.3)

0.1±0.1

△ 0.10
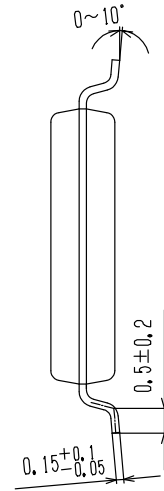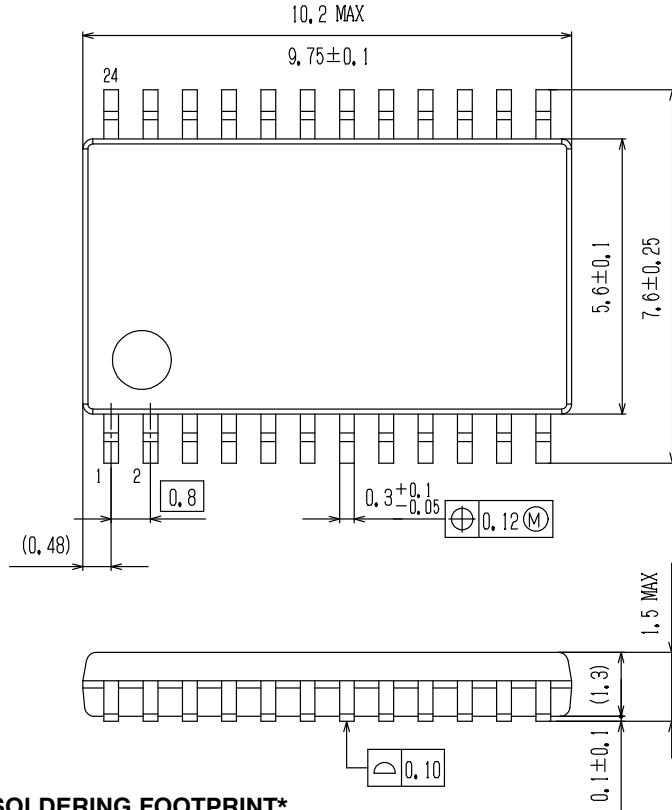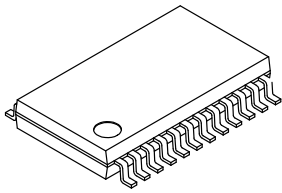
SOLDERING FOOTPRINT*

(Unit: mm)

1.00

7.00

0.80

0.42
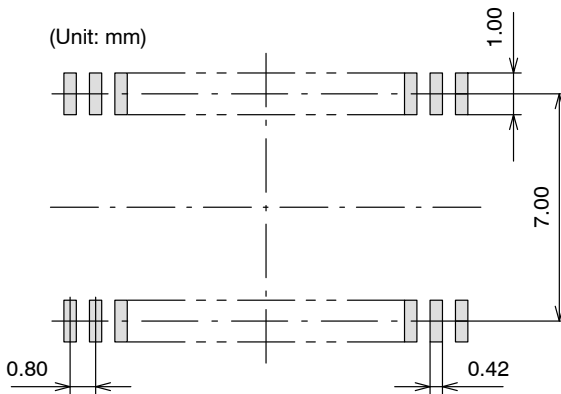
**GENERIC
MARKING DIAGRAM***
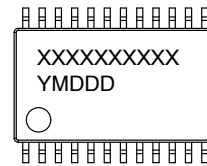
XXXXXXXXXX
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NOTE: The measurements are not to guarantee but for reference only.

  *For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot " ▪ ", may or may not be present.

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PUBLICATION ORDERING INFORMATION

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